

US201/A/B/C

CMOS IC

HIGH-SIDE POWER SWITCHES WITH FLAG

■ DESCRIPTION

The UTC **US201/A/B/C** series are 80mΩ high-side power switches. There's internal single low voltage N-Channel MOSFET which makes it an ideal for all USB applications. This MOSFET should be driven by a charge pump circuitry inside. Its switch on resistance is as low as 80mΩ which we know specially meets the drop voltage for USB applications.

The flag pin can output an open-drain fault flag to next controller. There're lots internal special ways for protecting the chip's operation.

When in hot-plug events, there's large current which can create the upstream voltage droop to match the USB's voltage droop requirements and soft-start for isolating the power source.

As soon as the die temperature is higher than 130°C, the internal shutdown circuit will work.

Only when there's a normal input voltage in the V_{IN} pin, the UVLO (under-voltage lockout, 1.3V/2.5V typ.) can make sure the chip is till in the off state.

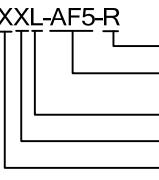
Because of the requirement of USB power the fault current should be ensured less than 0.6A/1.1A (UTC **US201/A**, single port) and 1.3A /1.5A (UTC **US201B/C**, dual ports).

■ FEATURES

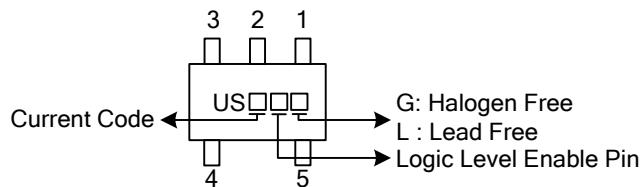
- * 80mΩ(Typ) N-Channel MOSFET
- * Supply Current:
 - Switch On : 25µA(Typ)
 - Switch Off : 1µA (Typ)
- * Load Current 500mA for US201 and 1.0A for US201A/B/C
- * Input Voltage from 2V ~ 5.5V
- * In Off-State: Output Voltage can be Higher than Input

■ ORDERING INFORMATION

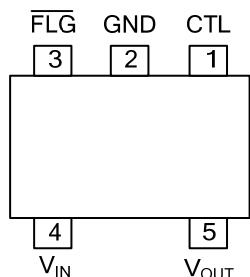
Ordering Number		Package	Packing
Lead Free	Halogen Free		
US201XXL-AF5-R	US201XXG-AF5-R	SOT-25	Tape Reel

 US201XXL-AF5-R	(1) R: Tape Reel (2) AF5: SOT-25 (3) G: Halogen Free, L: Lead Free (4) H: Active High, L: Active Low (5) Blank: 0.6A, A: 1.1A , B: 1.3A, C: 1.5A
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■ MARKING



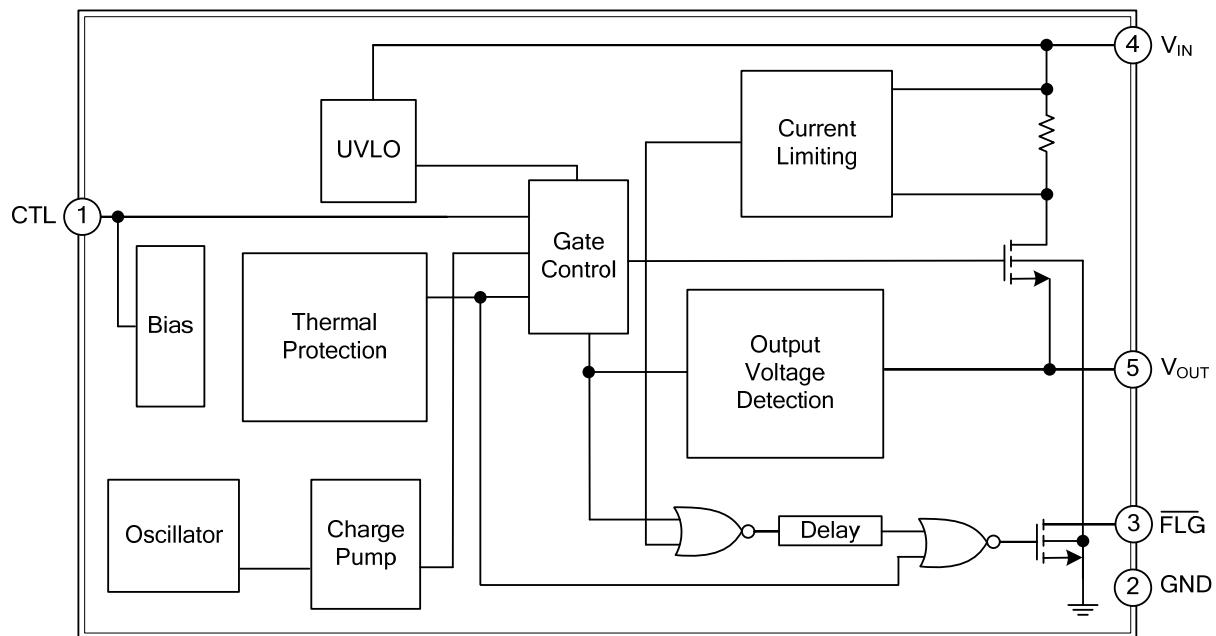
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO	PIN NAME	DESCRIPTION
1	CTL	Enable Input pin, H: High active, L: Low active
2	GND	Ground
3	FLG	Open-drain fault flag output
4	V _{IN}	Power input voltage
5	V _{OUT}	Output voltage

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING(Ta=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Supply Voltage		V_{CC}	6.5	V	
			+2 ~ +5.5 (Note 2)	V	
Input/Output Pins	CTL	V_{CTL}	-0.3~ +6.5	V	
			0 ~ +5.5 (Note 2)	V	
Input/Output Pins		V_{FLG}	6.5	V	
Power Dissipation (Ta=25°C)		P_D	0.25	W	
Junction Temperature		T_J	150	°C	
			-20 ~ +100 (Note 2)	°C	
Storage Temperature		T_{STG}	-65 ~ +150	°C	

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. The device is not guaranteed to function when it's beyond its operating conditions.

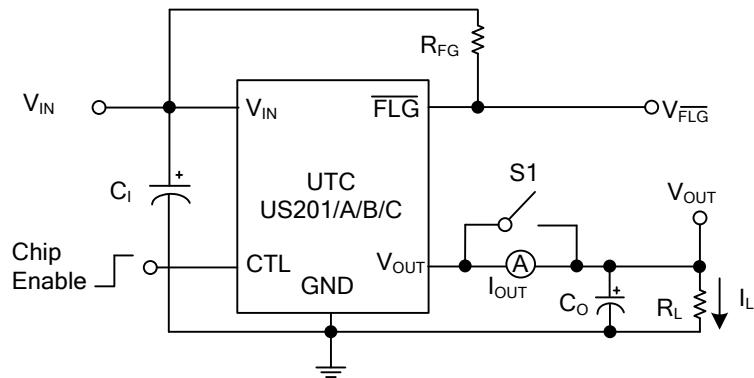
■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	250	°C/W

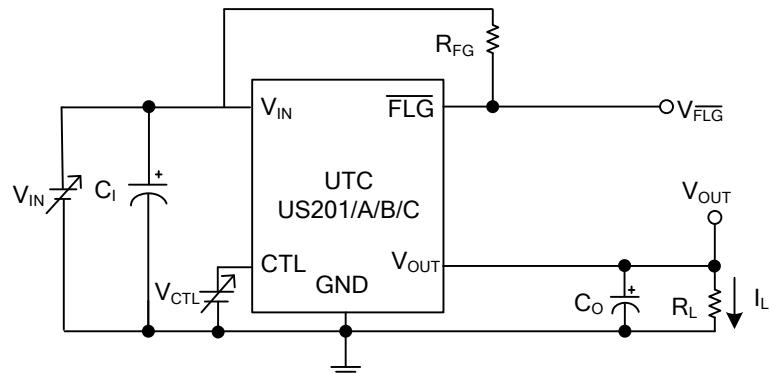
■ ELECTRICAL CHARACTERISTICS

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ENABLE INPUT							
CTL Threshold	Low	V _{IL}	V _{IN} =2V~5.5V, Switch OFF			0.8	V
	High	V _{IH}	V _{IN} =2V~5.5V, Switch ON	2.0			V
CTL Input Current	I _{I(CTL)}	V _{CTL} =0V~5.5V		0.01			μA
UNDER VOLTAGE LOCK							
Under-Voltage Lockout	V _{UVLO}	V _{IN} increasing	US201/ US201A	1.3			V
			US201B/ US201C	2.5			
Under-Voltage Hysteresis	ΔV _{UVLO}	V _{IN} decreasing		0.1			V
SUPPLY CURRENT							
Supply Current	I _{SW(ON)}	Switch on, V _{OUT} =OPEN			25	45	μA
	I _{SW(OFF)}	Switch off, V _{OUT} =OPEN			0.1	1	μA
Output Leakage Current	I _{O(LEAK)}	V _{CTL} =0V, R _{LOAD} =0Ω		0.5	10		μA
CURRENT LIMIT							
Current Limit	I _{LIMIT}		US201	0.6	0.8	1.1	A
			US201A	1.1	1.5	1.9	A
			US201B	1.3	1.7	2.1	A
			US201C	1.5	2.0	2.4	A
Short Circuit Fold-Back Current	I _{SC(FB)}	V _{OUT} =0V, measured prior to thermal shutdown	US201		0.8		A
			US201A		1.0		A
			US201B		1.0		A
			US201C		1.3		A
POWER SWITCH							
Switch ON Resistance	R _{DS(ON)}	I _{OUT} = 500mA	US201	80	110		mΩ
		I _{OUT} =1.0A	US201A/B/C	80	110		mΩ
Output Turn-ON Rise Time	t _{ON(RISE)}	10% ~ 90% of V _{OUT} rising		400			μs
OVER CURRENT FLAG							
FLAG OFF Current	I _{FLG(OFF)}	V _{FLG} =5V		0.01	1		μA
FLAG Output Resistance	R _{FLG}	I _{SINK} =1mA		20	400		Ω
FLAG Delay Time	t _D	From fault condition to FLG assertion	2	10	15		ms
THERMAL SHUTDOWN							
Thermal Shutdown Protection	T _{SD}			130			°C
Thermal Shutdown Hysteresis	ΔT _{SD}			20			°C

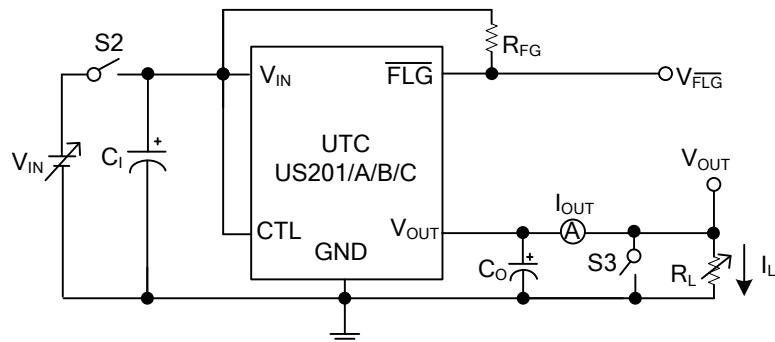
■ TEST CIRCUIT



Turn-On & Off Response, Flag Response

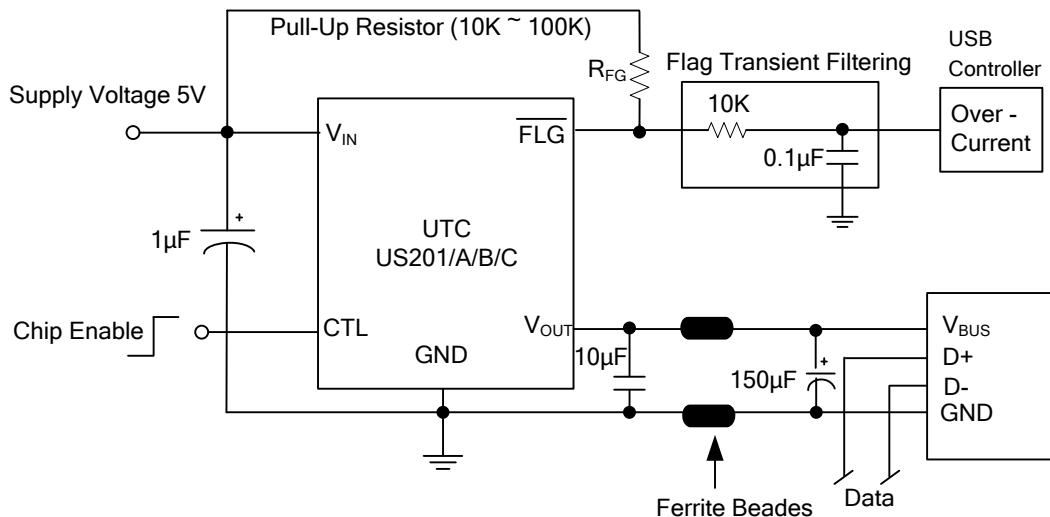


UVLO at Rising & Falling



Current Limit vs. Input Voltage, Inrush Current Response,
Current Limit Transient Response

■ TYPICAL APPLICATION CIRCUIT



Note. A low-ESR 150μF aluminum electrolytic or tantalum between **V_{OUT}** and GND is strongly recommended to meet the 330mV maximum droop requirement in the hub **V_{BUS}**.

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